# High-voltage Switching Transistor (-400V, -0.5A)

# 2SA1812 / 2SA1727 / 2SA1776

# Features

- 1) High breakdown voltage, BVcEo=-400V.
- 2) Low saturation voltage, typically  $V_{CE (sat)} = -0.3V$  at  $I_C / I_B = -100 \text{mA} / -10 \text{mA}$ .
- 3) High switching speed, typically tf :  $1\mu s$  at Ic = -100mA.
- 4) Wide SOA (safe operating area).

# ● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit		
Collector-base voltage		Vсво	-400	V		
Collector-emitter voltage		VCEO	-400	V		
Emitter-base voltage		VEBO	<del>-</del> 7	V		
Collector current		lc	-0.5	A (DC)		
		IC IC	-1.0	A (Pulse)	*1	
Collector power dissipation	2SA1812		0.5	W		
			2	W	*2	
	2SA1727	Pc	1	W		
			10	W (Tc=25°C)		
	2SA1776		1	W	*3	
Junction temperature		Tj	150	°C		
Storage temperature		Tstg	-55 to +150	°C		

**<sup>★1</sup>** Single pulse **★2** When mounted on a 40×40×0.7mm ceramic board.

# ● Packaging specifications and hFE

Туре	2SA1812	2SA1727	2SA1776	
Package	MPT3	CPT3	ATV	
hfe	PQ	PQ	PQ	
Marking	AJ*	_	_	
Code	T100	TL	TV2	
Basic ordering unit (pieces)	3000	3000	2500	

<sup>★</sup> Denotes here

# ● Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	ВУсво	-400	_	_	V	Ic=-50μA	
Collector-emitter breakdown voltage	BVceo	-400	_	_	V	Ic=-1mA	
Emitter-base breakdown voltage	ВУево	-7	_	_	V	I <sub>E</sub> = -50μA	
Collector cutoff current	Ісво	<b>—</b>	_	-10	μΑ	V <sub>CB</sub> =-400V	
Emitter cutoff current	ІЕВО	<b> </b>	_	-10	μΑ	V <sub>EB</sub> = -6V	
DC current tranfer ratio	hfe	82	150	270	_	Vc=-5V, lc= 50mA	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	<b>—</b>	_	-1	V	Ic/I <sub>B</sub> = -100mA / -10mA	
Base-emitter saturation voltage	V <sub>BE</sub> (sat)	T —	_	-1.2	V	Ic/I <sub>B</sub> = -100mA / -10mA	
Transition frequency	f⊤	_	12	_	MHz	$V_{CB} = -5V$ , $I_E = 50mA$ , $f = 5MHz$	
Output capacitance	Cob	<b>—</b>	18	_	pF	$V_{CE} = -10V$ , $I_{E} = 0A$ , $f = 1MHz$	
Turn-on time	ton	<b>—</b>	0.6	_	μs	$lc = -100$ mA. $R_L = 1.5$ k $\Omega$	
Storage time	tstg	T —	2.7	_	μs	$  I_{B1} = -I_{B2} = -10$ mA	
Fall time	<b>t</b> f	<u> </u>	1	_	μs	Vcc <u>to</u> –150V	

 $<sup>\</sup>ensuremath{ \mbox{\$} 3}$  When t=1.7 mm and the foil collector area on the PC board is  $1 cm^2$  or greater.

### Electrical characteristic curves

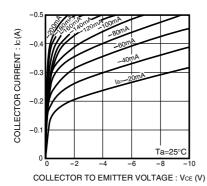


Fig.1 Grouded emitter output characteristics

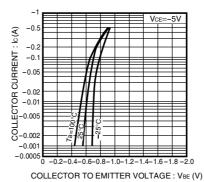


Fig.2 Grounded emitter propagation characteristics

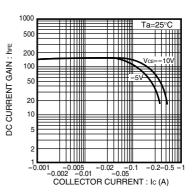


Fig.3 DC current gain vs. collector current (I)

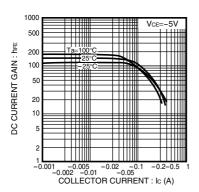


Fig.4 DC current gain vs. collector current (II)

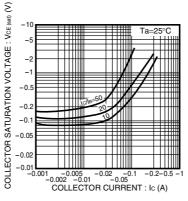


Fig.5 Collector-emitter saturation voltage vs. collector current

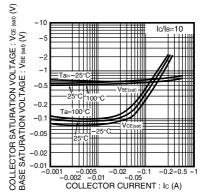


Fig.6 Collector-emitter saturation voltage vs. collector current Base-emitter saturation voltage vs. collector current

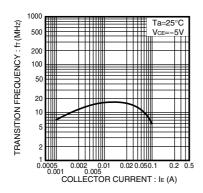


Fig.7 TRANSITION FREQUENCY vs. EMITTER CURRENT

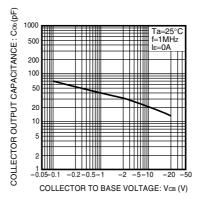
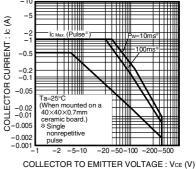


Fig.8 Collector output capacitance vs. collector-base voltage



COLLECTOR TO EMITTER VOLTAGE: VCE (V)

Fig.9 Safe operating area (2SA1812)

TIME : t (s)

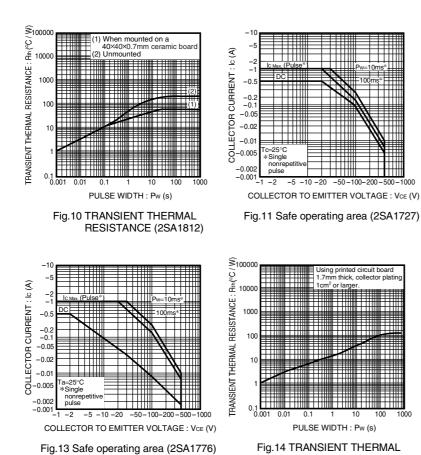
RESISTANCE (2SA1727)

Fig.12 TRANSIENT THERMAL

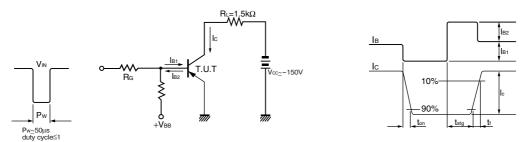
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TRANSIENT THERMAL RESISTANCE:



# •Switching characteristic measurement circuit



RESISTANCE (2SA1776)

Fig.15 Switching characteristic measurement circuit

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